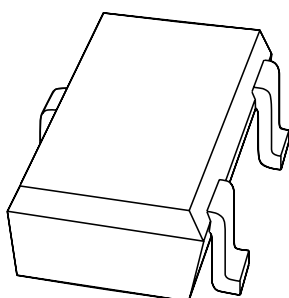


# DATA SHEET



## **PDT C114 YU** NPN resistor-equipped transistor

Product specification

1999 Apr 20

NPN resistor-equipped transistor

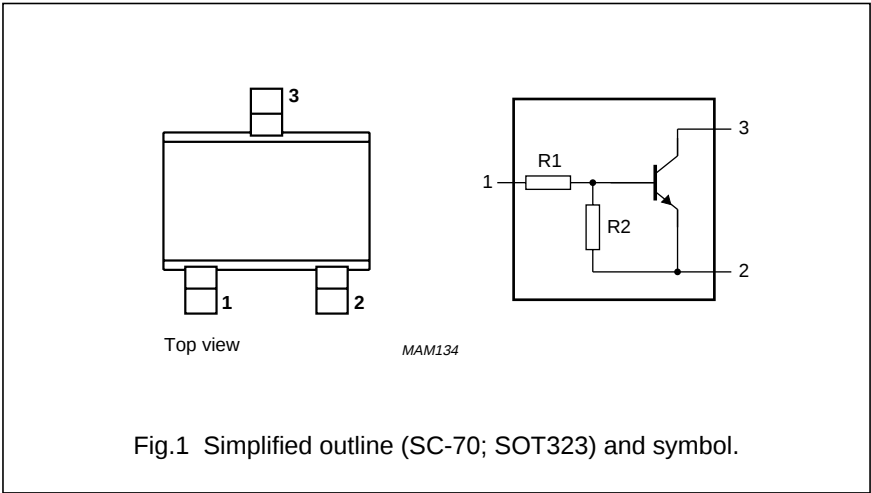
PDTC114YU

FEATURES

- Built-in bias resistors R1 and R2 (typ. 10 kΩ and 47 kΩ respectively)
- Simplification of circuit design
- Reduces number of components and board space.

APPLICATIONS

- Especially suitable for space reduction in interface and driver circuits
- Inverter circuit configurations without use of external resistors.

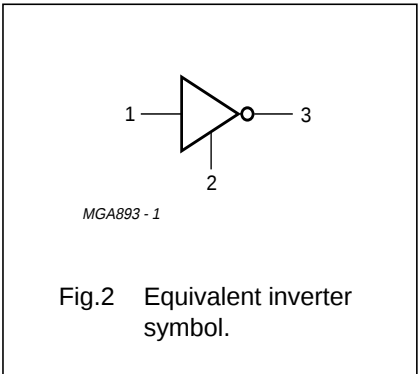


DESCRIPTION

NPN resistor-equipped transistor in an SC-70 (SOT323) plastic package.

PINNING

| PIN | DESCRIPTION      |
|-----|------------------|
| 1   | base/input       |
| 2   | emitter/ground   |
| 3   | collector/output |



MARKING

| TYPE NUMBER | MARKING CODE <sup>(1)</sup> |
|-------------|-----------------------------|
| PDTC114YU   | *30                         |

Note

1. \* = -: Made in Hong Kong.  
\* = t: Made in Malaysia.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL           | PARAMETER                     | CONDITIONS                       | MIN. | MAX. | UNIT |
|------------------|-------------------------------|----------------------------------|------|------|------|
| V <sub>CBO</sub> | collector-base voltage        | open emitter                     | –    | 50   | V    |
| V <sub>CEO</sub> | collector-emitter voltage     | open base                        | –    | 50   | V    |
| V <sub>EBO</sub> | emitter-base voltage          | open collector                   | –    | 10   | V    |
| V <sub>I</sub>   | input voltage                 |                                  |      |      |      |
|                  | positive                      |                                  | –    | 40   | V    |
|                  | negative                      |                                  | –    | –6   | V    |
| I <sub>O</sub>   | output current (DC)           |                                  | –    | 100  | mA   |
| I <sub>CM</sub>  | peak collector current        |                                  | –    | 100  | mA   |
| P <sub>tot</sub> | total power dissipation       | T <sub>amb</sub> ≤ 25 °C; note 1 | –    | 200  | mW   |
| T <sub>stg</sub> | storage temperature           |                                  | –65  | +150 | °C   |
| T <sub>j</sub>   | junction temperature          |                                  | –    | 150  | °C   |
| T <sub>amb</sub> | operating ambient temperature |                                  | –65  | +150 | °C   |

Note

1. Refer to SC-70 (SOT323) standard mounting conditions.

## NPN resistor-equipped transistor

## PDTC114YU

## THERMAL CHARACTERISTICS

| SYMBOL        | PARAMETER                                   | CONDITIONS | VALUE | UNIT |
|---------------|---------------------------------------------|------------|-------|------|
| $R_{th\ j-a}$ | thermal resistance from junction to ambient | note 1     | 625   | K/W  |

## Note

1. Refer to SC-70 (SOT323) standard mounting conditions.

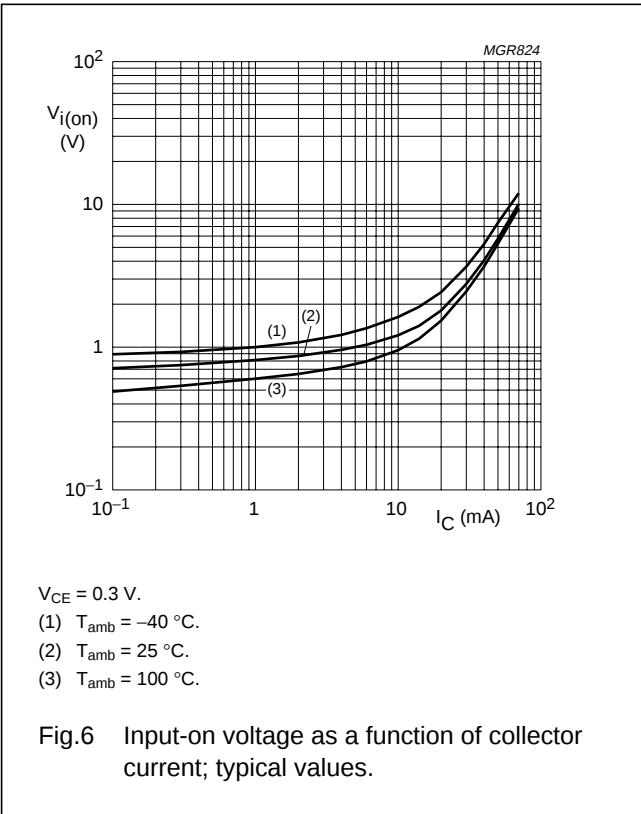
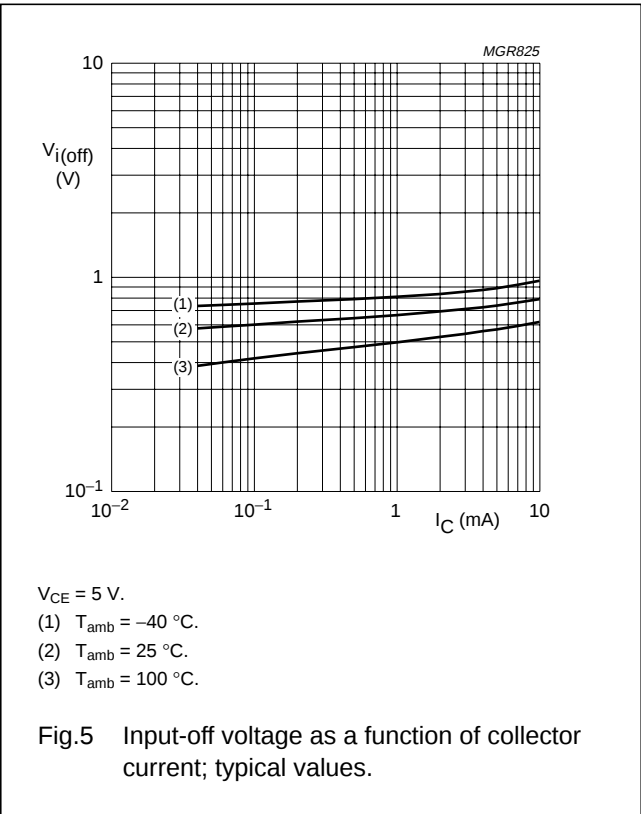
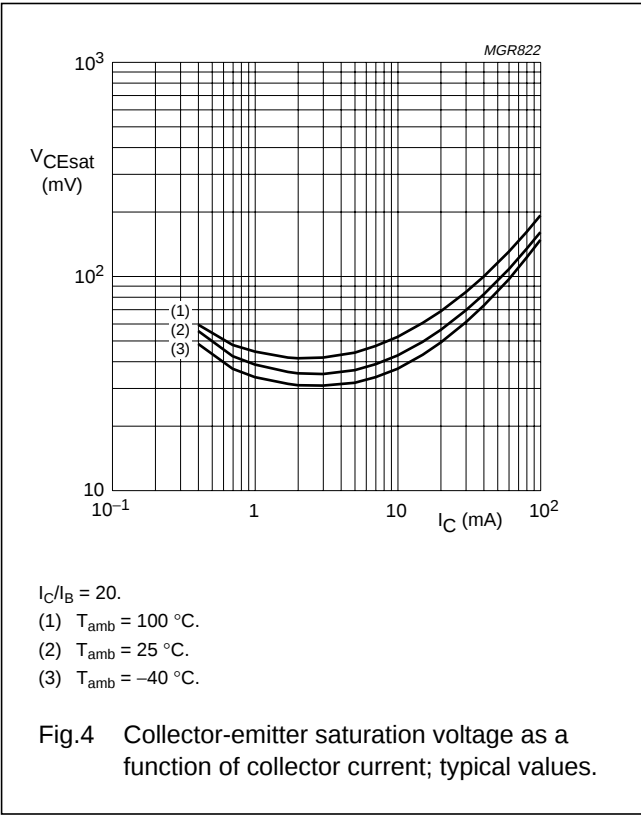
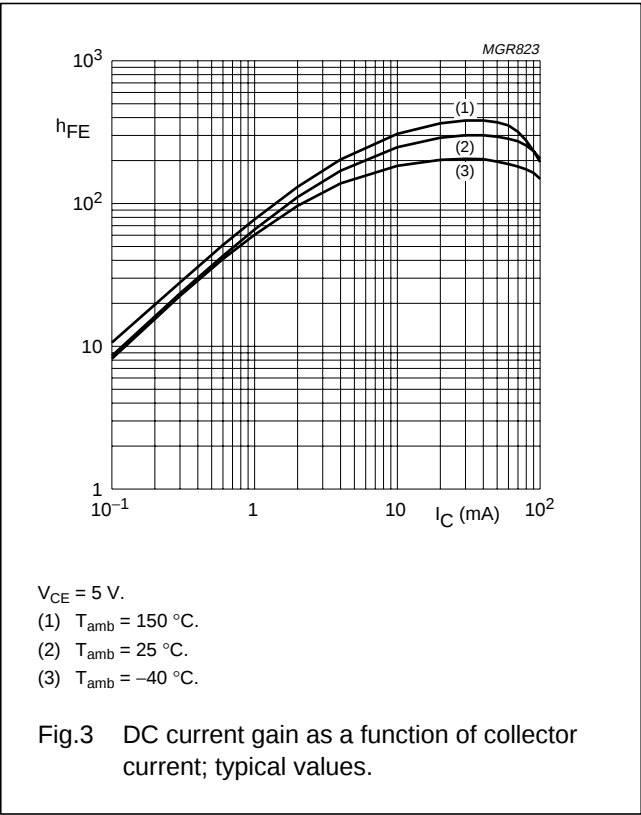
## CHARACTERISTICS

$T_{amb} = 25\text{ °C}$  unless otherwise specified.

| SYMBOL          | PARAMETER                            | CONDITIONS                                                    | MIN. | TYP. | MAX. | UNIT          |
|-----------------|--------------------------------------|---------------------------------------------------------------|------|------|------|---------------|
| $I_{CBO}$       | collector cut-off current            | $I_E = 0$ ; $V_{CB} = 50\text{ V}$                            | –    | –    | 100  | nA            |
| $I_{CEO}$       | collector cut-off current            | $I_B = 0$ ; $V_{CE} = 30\text{ V}$                            | –    | –    | 1    | $\mu\text{A}$ |
|                 |                                      | $I_B = 0$ ; $V_{CE} = 30\text{ V}$ ; $T_j = 150\text{ °C}$    | –    | –    | 50   | $\mu\text{A}$ |
| $I_{EBO}$       | emitter cut-off current              | $I_C = 0$ ; $V_{EB} = 5\text{ V}$                             | –    | –    | 150  | $\mu\text{A}$ |
| $h_{FE}$        | DC current gain                      | $I_C = 5\text{ mA}$ ; $V_{CE} = 5\text{ V}$                   | 100  | –    | –    |               |
| $V_{CEsat}$     | collector-emitter saturation voltage | $I_C = 5\text{ mA}$ ; $I_B = 0.25\text{ mA}$                  | –    | –    | 100  | mV            |
| $V_{i(off)}$    | input-off voltage                    | $I_C = 100\text{ }\mu\text{A}$ ; $V_{CE} = 5\text{ V}$        | –    | 0.7  | 0.5  | V             |
| $V_{i(on)}$     | input-on voltage                     | $I_C = 1\text{ mA}$ ; $V_{CE} = 0.3\text{ V}$                 | 1.4  | 0.8  | –    | V             |
| R1              | input resistor                       |                                                               | 7    | 10   | 13   | $k\Omega$     |
| $\frac{R2}{R1}$ | resistor ratio                       |                                                               | 3.7  | 4.7  | 5.7  |               |
| $C_c$           | collector capacitance                | $I_E = I_e = 0$ ; $V_{CB} = 10\text{ V}$ ; $f = 1\text{ MHz}$ | –    | –    | 2.5  | pF            |

NPN resistor-equipped transistor

PDTC114YU



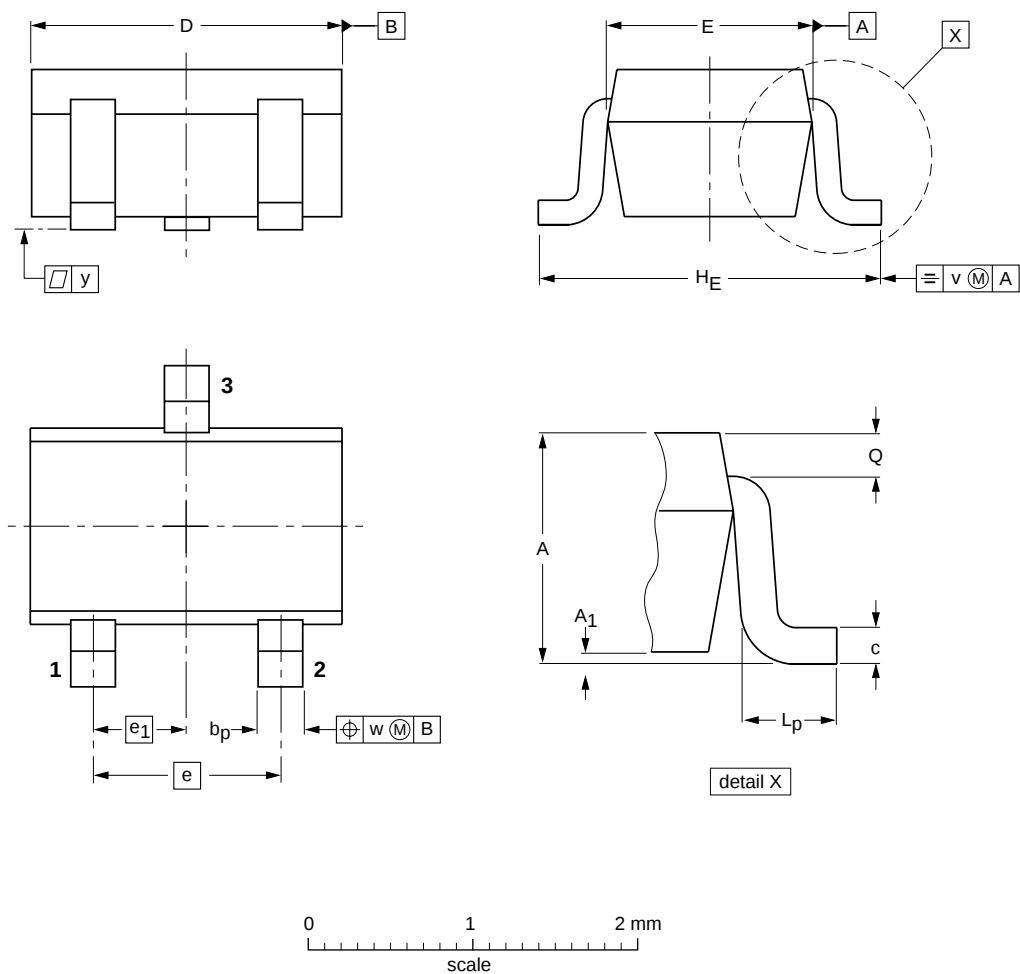
NPN resistor-equipped transistor

PDTC114YU

PACKAGE OUTLINE

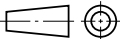
Plastic surface mounted package; 3 leads

SOT323



DIMENSIONS (mm are the original dimensions)

| UNIT | A          | A <sub>1</sub><br>max | b <sub>p</sub> | c            | D          | E            | e   | e <sub>1</sub> | H <sub>E</sub> | L <sub>p</sub> | Q            | v   | w   |
|------|------------|-----------------------|----------------|--------------|------------|--------------|-----|----------------|----------------|----------------|--------------|-----|-----|
| mm   | 1.1<br>0.8 | 0.1                   | 0.4<br>0.3     | 0.25<br>0.10 | 2.2<br>1.8 | 1.35<br>1.15 | 1.3 | 0.65           | 2.2<br>2.0     | 0.45<br>0.15   | 0.23<br>0.13 | 0.2 | 0.2 |

| OUTLINE<br>VERSION | REFERENCES |       |       |  | EUROPEAN<br>PROJECTION                                                                | ISSUE DATE |
|--------------------|------------|-------|-------|--|---------------------------------------------------------------------------------------|------------|
|                    | IEC        | JEDEC | EIAJ  |  |                                                                                       |            |
| SOT323             |            |       | SC-70 |  |  | 97-02-28   |

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NPN resistor-equipped transistor

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PDTC114YU

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**DEFINITIONS**

| <b>Data Sheet Status</b>                                                                                                                                                                                                                                                                                                                                                                                                                                  |                                                                                       |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------|
| Objective specification                                                                                                                                                                                                                                                                                                                                                                                                                                   | This data sheet contains target or goal specifications for product development.       |
| Preliminary specification                                                                                                                                                                                                                                                                                                                                                                                                                                 | This data sheet contains preliminary data; supplementary data may be published later. |
| Product specification                                                                                                                                                                                                                                                                                                                                                                                                                                     | This data sheet contains final product specifications.                                |
| <b>Limiting values</b>                                                                                                                                                                                                                                                                                                                                                                                                                                    |                                                                                       |
| Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability. |                                                                                       |
| <b>Application information</b>                                                                                                                                                                                                                                                                                                                                                                                                                            |                                                                                       |
| Where application information is given, it is advisory and does not form part of the specification.                                                                                                                                                                                                                                                                                                                                                       |                                                                                       |

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NPN resistor-equipped transistor

PDTC114YU

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